IN THE CLAIMS

Please amend the claims as follows:

- (Original) A quartz glass cylinder for producing an optical component, comprising an inner bore which is mechanically treated to a final dimension and provided with an etched structure due to an etching treatment following mechanical treatment, characterized in that the etched structure comprises cracks having a depth of not more than 2.0 mm and a width of not more than 100 μm.
- 2. (Original) The quartz glass cylinder according to claim 1, characterized in that the etched structure comprises cracks having a depth of not more than 1.0 mm and a width of not more than 50 μ m.
- 3. (Original) The quartz glass cylinder according to claim 1, characterized in that the etched structure comprises cracks having a depth of not more than 0.5 mm and a width of not more than 20 μ m.
- 4. (Amended) The quartz glass cylinder according to <u>claim 1</u> [any one of the preceding claims], characterized in that the etched structure comprises cracks having a depth of at least 30 μm and a width of at least 5 μm.
- 5. (Amended) The quartz glass cylinder according to <u>claim 1</u> [any one of the preceding <u>claims</u>], characterized by an outer diameter of at least 150 mm.
- 6. (Amended) A method for producing a quartz glass cylinder comprising an inner bore, according to <u>claim 1</u> [any one of claims 1 to 5], in that the inner bore of the quartz glass cylinder is mechanically treated to a final dimension and subsequently subjected to an etching treatment, characterized in that the mechanical treatment comprises a

plurality of subsequent removal processes with a successively smaller removal depth, the inner bore comprising subsurface cracks of a depth of not more than 2 mm after the last removal process, and that the inner bore is subsequently subjected to an etching treatment such that an etching removal with a depth of not more than 50 µm is achieved.

- 7. (Original) The method according to claim 6, characterized in that the etching treatment yields an etching removal with a depth of not more than 25 μm.
- 8. (Original) The method according to claim 6, characterized in that the etching treatment yields an etching removal with a depth of not more than $10 \mu m$.
- 9. (Amended) The method according to <u>claim 6</u> [any one of claims 6 to 8], characterized in that the etching treatment yields an etching removal with a depth of at least 2.5 μm.
- 10. (Amended) The method according to <u>claim 6</u> [any one of claims 6 to 9], characterized in that the etching treatment includes a first etching step in an etching solution containing hydrofluoric acid, and a second etching step in an etching solution containing nitric acid.
- 11. (Amended) The method according to <u>claim 6</u> [any one of claims 6 to 10], characterized in that the etching treatment is carried out at a mean etching rate of not more than 3 μm/min.
- 12. (Original) The method according to claim 11, characterized in that the mean etching rate is not more than 1 μm/min.
- 13. (Original) The method according to claim 11, characterized in that the mean etching rate is not more than 0.1 μm/min.

- 14. (Amended) Use of a quartz glass cylinder according to <u>claim 1</u> [any one of the <u>preceding claims 1 to 5</u>] for producing a preform for an optical fiber in an RIC method by collapsing the cylinder onto a core rod and by simultaneously elongating said cylinder with formation of the preform.
- 15. (Amended) Use of a quartz glass cylinder according to <u>claim 1</u> [any one of the <u>preceding claims 1 to 5</u>] for producing an optical fiber in an RIC-ODD method by collapsing the cylinder onto a core rod and by simultaneously elongating said cylinder with formation of the fiber.